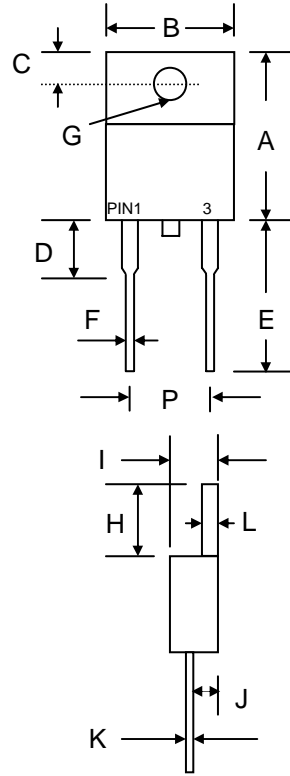


#### Features

- Schottky Barrier Chip
- Ideally Suited for Automatic Assembly
- Low Power Loss, High Efficiency
- Surge Overload Rating to 100A Peak
- For Use in Low Voltage Application
- Guard Ring Die Construction
- Plastic Case Material has UL Flammability Classification Rating 94V-O

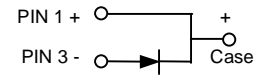
#### Mechanical Data

- Case: ITO-220AC, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: See Diagram
- Mounting Position: Any
- **Lead Free: For RoHS / Lead Free Version**



ITO-220AC		
Dim	Min	Max
A	14.50	15.50
B	9.50	10.50
C	2.55	2.90
D	3.30	4.30
E	13.00	14.00
F	0.30	0.90
G	3.00 Ø	3.80 Ø
H	6.30	7.30
I	4.20	4.80
J	2.50	2.90
K	0.47	0.75
L	2.50	3.10
P	4.88	5.28

All Dimensions in mm



#### Maximum Ratings and Electrical Characteristics @ $T_A=25^\circ\text{C}$ unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load.  
For capacitive load, derate current by 20%.

Characteristic	Symbol	MBRF 1040	MBRF 1045	MBRF 1050	MBRF 1060	MBRF 1080	MBRF 10100	MBRF 10150	MBRF 10200	Units
Peak Repetitive Reverse Voltage	$V_{RRM}$	40	45	50	60	80	100	150	200	V
Working Peak Reverse Voltage	$V_{RWM}$									
DC Blocking Voltage	$V_R$									
RMS Reverse Voltage	$V_{R(RMS)}$	28	31	35	42	56	70	105	140	V
Average Rectified Output Current @ $T_L = 100^\circ\text{C}$ (Note 1)	$I_o$	10.0								A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	$I_{FSM}$	100				120				A
Forward Voltage @ $I_F = 10\text{A}$	$V_{FM}$	0.70		0.80		0.85		0.92		V
Peak Reverse Current @ $T_A = 25^\circ\text{C}$ At Rated DC Blocking Voltage @ $T_A = 100^\circ\text{C}$	$I_{RM}$	0.1								mA
		20								
Typical Junction Capacitance (Note 2)	$C_j$	350		280		200				pF
Typical Thermal Resistance (Note 1)	$R_{\theta JA}$	3.5				2.0				$^\circ\text{C/W}$
Operating and Storage Temperature Range	$T_j, T_{STG}$	-55 to +150							-55 to +175	$^\circ\text{C}$

Note: 1. Valid provided that leads are kept at ambient temperature at a distance of 9.5mm from the case.  
2. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

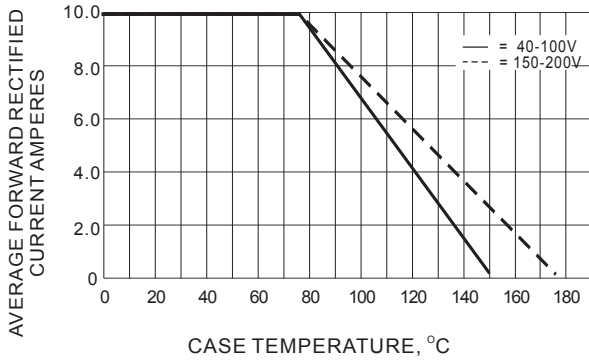


Fig.1- FORWARD CURRENT DERATING CURVE

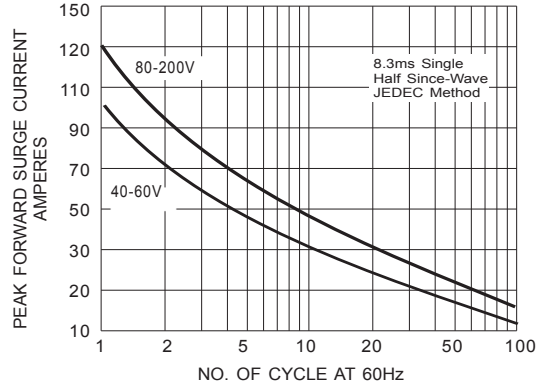


Fig.2- MAXIMUM NON-REPETITIVE SURGE CURRENT

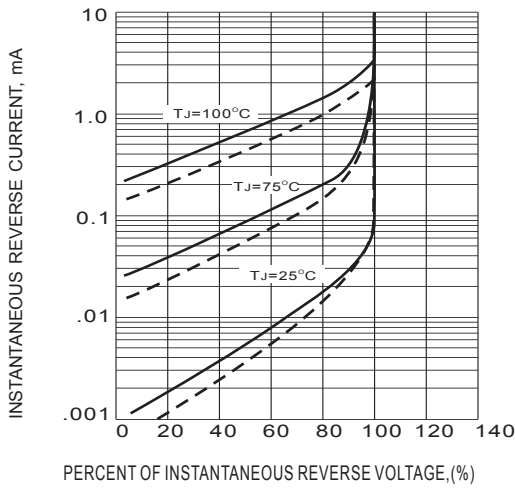


Fig.3- TYPICAL REVERSE CHARACTERISTICS

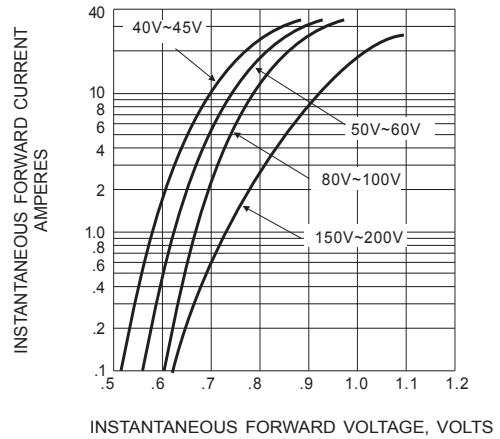


Fig.4- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS